



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Alessia Pavan, et al.

Title: **NON-VOLATILE MEMORY CELL COMPRISING
DIELECTRIC LAYERS HAVING A LOW DIELECTRIC
CONSTANT AND CORRESPONDING MANUFACTURING
PROCESS**

Application No.: 10/749,130

Filing Date: December 30, 2003

Examiner/ Unit: Amar Movva / 2891

Attorney Docket No.: 2110-099-03

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited in the United States Postal Service as First Class mail in an envelope addressed to: MS Amendments, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 24th day of March, 2008.

Signature

AMENDMENT AND RESPONSE UNDER 37 CFR §1.111

TO THE COMMISSIONER FOR PATENTS

Reconsideration of the above-referenced patent application is requested in view of the following amendments and remarks. Amendments to the claims are reflected in the listing of claims which begins on page 2 of this paper. Remarks in response to the Office Action mailed September 26, 2007 in the above-referenced patent application are set forth beginning on page 7 of this paper.